NSN 5962-01-357-6619

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View Online at https://aerobasegroup.com/nsn/5962-01-357-6619 **Body Length:**

Between 1.440 inches and 1.490 inches

Body Width:

Between 0.500 inches and 0.610 inches

Body Height:

0.225 inches

Operating Tempurature Range:

-55.0/+125.0 degrees celsius

Storage Tempurature Range:

-65.0/+150.0 degrees celsius

Features Provided:

Bipolar and programmable and w/enable and 3-state output and w/disable

Inclosure Material:

Ceramic

Inclosure Configuration:

Dual-in-line

Output Logic Form:

Transistor-transistor logic

Input Circuit Pattern:

17 input

Current Rating Per Characteristic:

180.00 milliamperes reverse current, dc absolute

Terminal Surface Treatment:

Solder

Voltage Rating And Type Per Characteristic:

7.0 volts power source

Capitance Rating Per Characteristic:

7.00 input picofarads and 17.00 output picofarads

Time Rating Per Chacteristic:

80.00 nanoseconds access

Memory Device Type:

Pal

Test Data Document:

96906-mil-std-883 standard (includes industry or association standards, individual manufactureer standards, etc.).

Terminal Type And Quantity:

28 printed circuit

Shelf Life:

N/a

Unit Of Measure:

Demilitarization:

Yes - demil/mli

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